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KA3882C/KA3883C SMPS Controller

Features

- Low Start Current 0.2mA (Typ)
- Operating Range Up To 500kHz
- Cycle by Cycle Current Limiting
- Under Voltage Lock Out With Hysteresis
- Short Shutdown Delay Time: Typ.100ns
- High Current Totem-Pole Output
- Output Swing Limiting: 22V

Description

The KA3882C/KA3883C is a fixed PWM controller for Off Line and DC to DC converter applications. The internal circuits include an UVLO, a low start up current circuit, a temperature compensated reference, a high gain error amplifier, a current sensing comparator, and the high current totem-pole output for driving a POWER MOSFET. Also the KA3882C/KA3883C provides low start-up current below 0.3mA and short shutdown delay time typ. 100ns. The KA3882C has the UVLO threshold of 16V (on) and 10V(off). The KA3883C is 8.4V(on) and 7.6V(off). The KA3882C and KA3883C can operate within 100% duty cycle.



Internal Block Diagram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Supply Voltage	Vcc	30	V
Output Current	lo	±1	A
Analog Inputs (pin 2, 3)	VI(ANA)	-0.3 to 6.3	V
Error Amp. Output Sink Current	ISINK(EA)	10	mA
Power Dissipation	PD	1	W
Thermal Resistance, Junction-to-Air (Note4) 8-SOP 8-DIP	Rθja	151 95	°C/W
Storage Temperature	T _{stg}	-65 ~ 150	°C

Electrical Characteristics

(V_{CC} = 15V, R_T = 10k Ω , C_T = 3.3nF, T_A = 0°C to +70°C ,Unless otherwise specified)

Parameter	Symbol	Conditions		Тур.	Max.	Unit
REFERENCE SECTION						
Output Voltage	Vref	TJ = 25°C, IO = 1mA		5.0	5.1	V
Line Regulation	$\Delta VREF$	VCC = 12V to 25V	-	6	20	mV
Load Regulation	$\Delta VREF$	IO = 1mA to 20mA	-	6	25	mV
Output Short Circuit	ISC	T _a = 25°C	-	-100	-180	mA
OSILLATOR SECTION						
Initial Accuracy	Fosc	TJ = 25°C	47	52	57	kHz
Voltage Stability	STv	VCC = 12V to 25V	-	0.2	1	%
Amplitude	Vosc	VPIN4, Peak to Peak	-	1.7	-	V
Discharge Current	IDISCHG	TJ = 25°C, Pin4 = 2V	7.8	8.3	8.8	mA
CURRENT SENSE SECTION						
Gain	Gv	(Note2, 3)	2.85	3	3.15	V/V
Maximum Input Signal	VI(MAX)	VPIN1 = 5V(Note2)	0.9	1.0	1.1	V
PSRR	PSRR	VCC = 12V to 25V (Note1, 2)	-	70	-	dB
Input Bias Current	IBIAS	-	-	-2	-10	uA
Delay to Output	TD	VPIN3 = 0 V to 2V (Note1)	-	100	200	ns

Electrical Characteristics (Continued)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
ERROR AMPLIFIER SECTION						
Input Voltage	Vi	TPIN1 = 2.5V	2.42	2.50	2.58	V
Input Bias Current	IBIAS	-		-0.3	-2	uA
Open Loop Gain	Gvo	Vo = 2V to 4V (Note1)	65	90	-	dB
Unity Gain Bandwidth	GBW	TJ= 25°C (Note1)	0.7	1	-	MHz
PSRR	PSRR	V _{CC} = 12V to 25V (Note1)	60	70	-	dB
Output Sink Current	ISINK	VPIN2 = 2.7V, VPIN1 = 1.1V	2	6	-	mA
Output Source Current	ISOURCE	VPIN2 = 2.3V, VPIN1 = 5.0V	-0.5	-0.8	-	mA
Output High Voltage	Voh	VPIN2 = 2.3V, R1 = $15k\Omega$ to GND	5	6	-	V
Output Low Voltage	Vol	$V_{PIN2} = 2.7V, R1 = 15k\Omega$ to Pin8	-	0.8	1.1	V
OUTPUT SECTION						
Output Low Level	Mai	ISINK = 20mA	-	0.1	0.4	V
	VOL	ISINK = 200mA	-	1.5	2.2	V
Output High Level	Vou	ISOURCE = 20mA	13	13.5	-	V
	VOH	ISOURCE = 200mA	12	13.5	-	V
Rise Time	tR	TJ = 25°C, C1 = 1nF (Note1)	-	40	100	ns
Fall Time	tF	TJ = 25°C, C1 = 1nF (Note1)	-	40	100	ns
Output Voltage Swing Limit	Volim	V _{CC} = 27V, C1 = 1nF	-	22	-	V
UNDER VOLTAGE LOCKOUT SECTION						
Start Threshold VTH	\/	KA3882C	15	16	17	V
	VIH	KA3883C	7.8	8.4	9.0	V
Min. Operating Voltage (After turn on) VTL	\/ _ 1	KA3882C	9	10	11	V
	VIL	KA3883C	7.0	7.6	8.2	V
PWM SECTION						
Maximum Duty Cycle	DMAX	KA3882C/KA3883C	94	96	100	%
Minimum Duty Cycle	DMIN	-	-	-	0	%
TOTAL STANDBY CURRENT						
Start-Up Current	IST	-	-	0.2	0.4	mA
Operating Supply Current	ICC	VPIN2 = VPIN3 = 0V		11	17	mA
VCC Zener Voltage	Vz	ICC = 25mA	-	29	-	V

(VCC = 15V, RT = 10k Ω , CT = 3.3nF, TA = 0°C to +70°C, Unless otherwise specified)

 * Adjust Vcc above the start threshold before setting at 15V

Notes :

1. These parameters, although guaranteed, are not 100% tested in production.

2. Parameter measured at trip point of latch with V2 = 0V.

3. Gain defined as: $G_V = \Delta V_{PIN1} \Delta V_{PIN3} (V_{PIN3} = 0 \text{ to } 0.8V)$

4. Junction-to-air thermal resistance test enviroments.

-. PCB information ;

Board thickness : 1.6mm , Board dimension : 76.2 X 114.3mm² , Ref. : EIA / JSED51-3 and EIA / JSED51-7

-. Board structure; Using the single layer PCB.

Mechanical Dimensions

Package



8-DIP

Mechanical Dimensions (Continued)

Package



Ordering Information

Product Number	Package	Operating Temperature		
KA3882C	8-DIP			
KA3882CD	8-SOP	0+70°C		
KA3883C	8-DIP	0~+70 C		
KA3883CD	8-SOP			

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